BOURNS®

- 20 W Pulsed Power Dissipation
- 100 V Capability
- 2 A Continuous Collector Current
- 4 A Peak Collector Current
- Customer-Specified Selections Available



MDTRAB

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING			VALUE	UNIT	
	TIPP31		40	v	
Collector base veltage $(I = 0)$	TIPP31A	V	60		
$Collector-base voltage (I_E = 0)$	TIPP31B	V CBO	80		
	TIPP31C		100		
	TIPP31		40	v	
Callester emitter veltere (I)	TIPP31A	M	60		
Collector-emitter voltage ($I_B = 0$)	TIPP31B	VCEO	80		
	TIPP31C		100		
Emitter-base voltage	V _{EBO}	5	V		
Continuous collector current			2	А	
Peak collector current (see Note 1)	I _{CM}	4	А		
Continuous base current	Ι _Β	1	А		
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)			0.8	W	
Pulsed power dissipation (see Note 3)	P _T	20	W		
Operating junction temperature range	Т _ј	-55 to +150	°C		
Storage temperature range	T _{stg}	-55 to +150	°C		
Lead temperature 3.2 mm from case for 10 seconds			260	°C	

NOTES: 1. This value applies for $t_p \leq 0.3$ ms, duty cycle $\leq 10\%.$

- 2. Derate linearly to 150°C case temperature at the rate of 6.4 mW/°C.
- 3. V_{CE} = 20 V, I_{C} = 1 A, t_{p} = 10 ms, duty cycle \leq 2%.

PRODUCT INFORMATION

TIPP31, TIPP31A, TIPP31B, TIPP31C NPN SILICON POWER TRANSISTORS



electrical characteristics at 25°C case temperature

	PARAMETER		TEST CONDITI	ONS	MIN	ТҮР	MAX	UNIT
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C = 5 mA (see Note 4)	I _B = 0	TIPP31 TIPP31A TIPP31B TIPP31C	40 60 80 100			V
I _{CES}	Collector-emitter cut-off current	$V_{CE} = 40 V$ $V_{CE} = 60 V$ $V_{CE} = 80 V$ $V_{CE} = 100 V$	$V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$	TIPP31 TIPP31A TIPP31B TIPP31C			0.2 0.2 0.2 0.2	mA
I _{CEO}	Collector cut-off current	$V_{CE} = 30 V$ $V_{CE} = 60 V$	Ι _Β = 0 Ι _Β = 0	TIPP31/31A TIPP31B/31C			0.3 0.3	mA
I _{EBO}	Emitter cut-off current	V _{EB} = 5 V	$I_{\rm C} = 0$				1	mA
h _{FE}	Forward current transfer ratio	$V_{CE} = 4 V$ $V_{CE} = 4 V$	$I_{\rm C} = 1 \text{ A}$ $I_{\rm C} = 2 \text{ A}$	(see Notes 4 and 5)	20 10			
V _{CE(sat)}	Collector-emitter saturation voltage	I _B = 375 mA	I _C = 2A	(see Notes 4 and 5)			1	V
V _{BE}	Base-emitter voltage	V _{CE} = 4 V	I _C = 2 A	(see Notes 4 and 5)			1.5	V
h _{fe}	Small signal forward current transfer ratio	V _{CE} = 10 V	I _C = 0.5 A	f = 1 kHz	20			
h _{fe}	Small signal forward current transfer ratio	V _{CE} = 10 V	I _C = 0.5 A	f = 1 MHz	3			

NOTES: 4. These parameters must be measured using pulse techniques, $t_p = 300 \ \mu s$, duty cycle $\leq 2\%$.

5. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.



MECHANICAL DATA

LP003 (TO-92)

3-pin cylindical plastic package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTE A: Lead dimensions are not controlled in this area.

MDXXAX

PRODUCT INFORMATION

MAY 1989 - REVISED SEPTEMBER 2002 Specifications are subject to change without notice.

TIPP31, TIPP31A, TIPP31B, TIPP31C NPN SILICON POWER TRANSISTORS



MECHANICAL DATA

LP003 (TO-92)

3-pin cylindical plastic package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



MDXXAR

PRODUCT INFORMATION

MAY 1989 - REVISED SEPTEMBER 2002 Specifications are subject to change without notice.

BOURNS®

TIPP31, TIPP31A, TIPP31B, TIPP31C NPN SILICON POWER TRANSISTORS

MECHANICAL DATA

LPR tape dimensions



MDXXAS

PRODUCT INFORMATION

MAY 1989 - REVISED SEPTEMBER 2002 Specifications are subject to change without notice.